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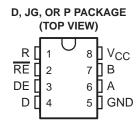
# SN55LBC176, SN65LBC176, SN65LBC176Q, SN75LBC176 DIFFERENTIAL BUS TRANSCEIVERS

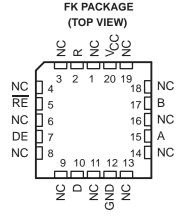
SLLS067G - AUGUST 1990 - REVISED APRIL 2006

- Bidirectional Transceiver
- Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-485-A and ISO 8482:1987(E)
- High-Speed Low-Power LinBiCMOS™ Circuitry
- Designed for High-Speed Operation in Both Serial and Parallel Applications
- Low Skew
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- Very Low Disabled Supply Current . . . 200
   μA Maximum
- Wide Positive and Negative Input/Output Bus Voltage Ranges
- Thermal-Shutdown Protection
- Driver Positive-and Negative-Current Limiting
- Open-Circuit Failsafe Receiver Design
- Receiver Input Sensitivity . . . ±200 mV Max
- Receiver Input Hysteresis . . . 50 mV Typ
- Operates From a Single 5-V Supply
- Glitch-Free Power-Up and Power-Down Protection
- Available in Q-Temp Automotive HighRel Automotive Applications Configuration Control / Print Support Qualification to Automotive Standards

#### description

The SN55LBC176, SN65LBC176, SN65LBC176Q, and SN75LBC176 differential bus transceivers are monolithic, integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. They are designed for balanced transmission lines and meet ANSI Standard TIA/EIA–485–A (RS-485) and ISO 8482:1987(E).





NC-No internal connection

#### **Function Tables**

#### DRIVER

INPUT	ENABLE	OUTI	PUTS
D	DE	Α	В
Н	Н	Н	L
L	Н	L	Н
X	L	Z	Z

#### RECEIVER

DIFFERENTIAL INPUTS  VID = VIA - VIB	ENABLE RE	OUTPUT R
V <sub>ID</sub> ≥ 0.2 V	L	Н
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	L	?
V <sub>ID</sub> ≤ −0.2 V	L	L
X	Н	Z
Open	L	Н

H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)



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### SN55LBC176, SN65LBC176, SN65LBC176Q, SN75LBC176 DIFFERENTIAL BUS TRANSCEIVERS

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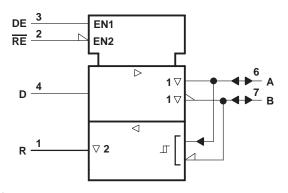
#### description (continued)

The SN55LBC176, SN65LBC176, SN65LBC176Q, and SN75LBC176 combine a 3-state, differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can externally connect together to function as a direction control. The driver differential outputs and the receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or  $V_{CC} = 0$ . This port features wide positive and negative common-mode voltage ranges, making the device suitable for party-line applications. Very low device supply current can be achieved by disabling the driver and the receiver.

These transceivers are suitable for ANSI Standard TIA/EIA-485 (RS-485) and ISO 8482 applications to the extent that they are specified in the operating conditions and characteristics section of this data sheet. Certain limits contained in TIA/EIA-485-A and ISO 8482:1987 (E) are not met or cannot be tested over the entire military temperature range.

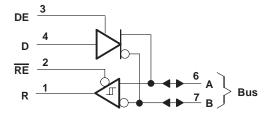
The SN55LBC176 is characterized for operation from -55°C to 125°C. The SN65LBC176 is characterized for operation from -40°C to 85°C, and the SN65LBC176Q is characterized for operation from -40°C to 125°C. The SN75LBC176 is characterized for operation from 0°C to 70°C.

### logic symbol†



#### † This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)

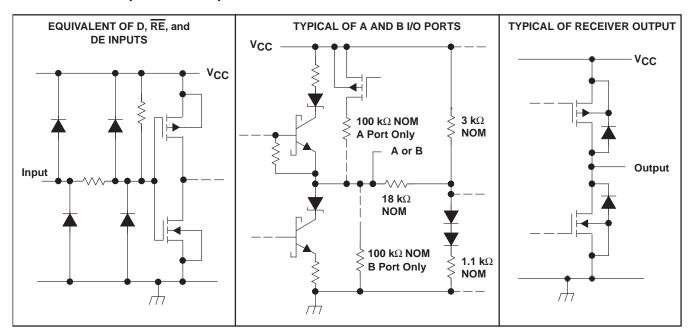


#### **AVAILABLE OPTIONS**

T <sub>A</sub>	PACKAGE	PART NUMBER	PART MARKING
200 1- 7000	SOP	SN75LBC176D	7LB176
0°C to 70°C	PDIP	SN75LBC176P	75LBC176
4000 1- 0500	SOP	SN65LBC176D	6LB176
-40°C to 85°C	PDIP	SN65LBC176P	65LBC176
4000 1- 44000	SOP	SN65LBC176QD	LB176Q
-40°C to 110°C	SOP	SN65LBC176QDR	LB176Q
5500 to 40500	LCCC	SNJ55LBC176FK	SNJ55LBC176FK
-55°C to 125°C	CDIP	SNJ55LBC176JG	SNJ55LBC176



#### schematics of inputs and outputs



### absolute maximum ratings†

Supply voltage, V <sub>CC</sub> (see Note 1)	7 V
Voltage range at any bus terminal	
Input voltage, $V_I$ (D, DE, R, or $\overline{RE}$ )	
Receiver output current, IO	± 10 mA
Continuous total power dissipation	See Dissipation Rating Table
Storage temperature range, T <sub>stq</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.

#### **DISSIPATION RATING TABLE**

PACKAGE	THERMAL MODEL	T <sub>A</sub> < 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	T <sub>A</sub> = 110°C POWER RATING
	Low K <sup>†</sup>	526 mW	5.0 mW/°C	301 mW	226 mW	_
D	High K <sup>‡</sup>	882 mW	8.4 mW/°C	504 mW	378 mW	_
Р		840 mW	8.0 mW/°C	480 mW	360 mW	_
JG		1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
FK		1375 mW	11.0 mW/°C	880 mW	715 mW	440 mW

 $<sup>^\</sup>dagger$  In accordance with the low effective thermal conductivity metric definitions of EIA/JESD 51–3.



<sup>‡</sup> In accordance with the high effective thermal conductivity metric definitions of EIA/JESD 51–7.

## SN55LBC176, SN65LBC176, SN65LBC176Q, SN75LBC176 DIFFERENTIAL BUS TRANSCEIVERS

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#### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>		4.75	5	5.25	V
Voltage at any bus terminal (separately or common mode), V <sub>I</sub> or V <sub>IC</sub>		-7		12	V
High-level input voltage, V <sub>IH</sub>	D, DE, and RE	2			V
Low-level input voltage, V <sub>IL</sub>	D, DE, and RE			8.0	V
Differential input voltage, V <sub>ID</sub> (see Note 2)		-12		12	V
High-level output current, I <sub>OH</sub>	Driver	-60			mA
	Receiver	-400			μΑ
Law law law tast something	Driver			60	
High-level output current, IOH  Low-level output current, IOL	Receiver			8	mA
Junction temperature, T <sub>J</sub>				140	°C
	SN55LBC176	-55		125	
Operating free cir temperature T.	SN65LBC176	-40		85	°C
Operating nee-all temperature, 1A	SN65LBC176Q	-40		125	C
Voltage at any bus terminal (separately or common mode), High-level input voltage, V <sub>IH</sub> Low-level input voltage, V <sub>ID</sub> Differential input voltage, V <sub>ID</sub> (see Note 2)  High-level output current, I <sub>OH</sub> Low-level output current, I <sub>OL</sub>	SN75LBC176	0		70	

NOTE 2: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.



#### **DRIVER SECTION**

## electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TE	ST CONDITIONS		MIN	MAX	UNIT
VIK	Input clamp voltage	I <sub>I</sub> = –18 mA			-1.5		V
VO	Output voltage	IO = 0			0	6	V
VOD1	Differential output voltage	IO = 0			1.5	6	V
V <sub>OD2</sub>	Differential output voltage	R <sub>L</sub> = 54 $\Omega$ , See Note 3	See Figure 1,	55LBC176, 65LBC176, 65LBC176Q	1.1		٧
				1.5 6    55LBC176, 65LBC176, 65LBC176Q   1.1   55LCB176, 65LCB176, 65LCB176, 65LCB176Q   1.1   55LBC176Q   1.5   5   5			
V <sub>OD3</sub>	Differential output voltage	V <sub>test</sub> = -7 V to 12 V, See Note 3	55LCB176, See Figure 2. 65LCB176,		1.1		V
				75LBC176	1.5	5	
Δ  V <sub>OD</sub>	Change in magnitude of differential output voltage †			•	-0.2	0.2	٧
Voc	Common-mode output voltage	$R_L = 54 \Omega$ or 100 $\Omega$ ,	See Figure 1		-1	3	V
Δ  V <sub>OC</sub>	Change in magnitude of common-mode output voltage†			-0.2	0.2	٧	
	•	Output disabled,	V <sub>O</sub> = 12 V			1	
IO	Output current	See Note 4	V <sub>O</sub> = -7 V		-0.8		mA
lιΗ	High-level input current	V <sub>I</sub> = 2.4 V			-100		μΑ
I <sub>I</sub> L	Low-level input current	V <sub>I</sub> = 0.4 V			-100		μΑ
		$V_O = -7 V$			-250		
l.	Object sizes it autout some	V <sub>O</sub> = 0			-150		4
los	Short-circuit output current	$V_O = V_{CC}$				050	mA
		V <sub>O</sub> = 12 V				250	
			Receiver disabled	55LBC176, 65LBC176Q		1.75	
	Complex grows at	$V_I = 0$ or $V_{CC}$ ,	and driver enabled	65LBC176, 75LBC176		1.5	4
Icc	Supply current	No load 55LBC176,	Receiver and driver	55LBC176, 65LBC176Q		0.25	mA
			disabled			0.2	

 $<sup>^{\</sup>dagger}\Delta$  | V<sub>OD</sub> | and  $\Delta$  | V<sub>OC</sub> | are the changes in magnitude of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input changes from a high level to a low level.

NOTES: 3. This device meets the  $V_{\mbox{OD}}$  requirements of TIA/EIA-485-A above 0°C only.



<sup>4.</sup> This applies for both power on and off; refer to TIA/EIA-485-A for exact conditions.

## SN55LBC176, SN65LBC176, SN65LBC176Q, SN75LBC176 DIFFERENTIAL BUS TRANSCEIVERS

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## switching characteristics over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		TEST CONDITIONS		SN55LBC176 SN65LBC176Q		SN65LBC176 SN75LBC176			UNIT			
				MIN	TYP	MAX	MIN	TYP†	MAX			
t <sub>d</sub> (OD)	Differential output delay time			8		31	8		25	ns		
t <sub>t</sub> (OD)	Differential output transition time	$R_L = 54 \Omega$ , See Figure 3	_	_	$C_L = 50 pF$ ,		12			12		ns
t <sub>sk(p)</sub>	Pulse skew (  t <sub>d(ODH)</sub> - t <sub>d(ODL)</sub>  )						6		0	6	ns	
tPZH	Output enable time to high level	$R_L = 110 \Omega$ ,	See Figure 4			65			35	ns		
tPZL	Output enable time to low level	$R_L = 110 \Omega$ ,	See Figure 5			65			35	ns		
tPHZ	Output disable time from high level	$R_L = 110 \Omega$ ,	See Figure 4			105			60	ns		
t <sub>PLZ</sub>	Output disable time from low level	$R_L = 110 \Omega$ ,	See Figure 5			105	·	·	35	ns		

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

#### **SYMBOL EQUIVALENTS**

OTHIDOL EQUIVALENTO						
DATA SHEET PARAMETER	RS-485					
Vo	V <sub>oa</sub> , V <sub>ob</sub>					
∣V <sub>OD1</sub> ∣	V <sub>O</sub>					
∣V <sub>OD2</sub> ∣	$V_t (R_L = 54 \Omega)$					
V <sub>OD3</sub>	V <sub>t</sub> (test termination measurement 2)					
Δ V <sub>OD</sub>	$   \vee_t   -   \overline{\vee}_t   $					
Voc	V <sub>os</sub>					
∆ Voc	$ V_{OS} - \overline{V}_{OS} $					
los	None					
lo	I <sub>ia</sub> , I <sub>ib</sub>					

#### **RECEIVER SECTION**

## electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

	PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V <sub>IT+</sub>	Positive-going input threshold voltage	V <sub>O</sub> = 2.7 V,	$I_{O} = -0.4 \text{ mA}$				0.2	V
VIT-	Negative-going input threshold voltage	V <sub>O</sub> = 0.5 V,	I <sub>O</sub> = 8 mA		-0.2‡			V
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT+</sub> – V <sub>IT</sub> _) (see Figure 4)					50		mV
VIK	Enable-input clamp voltage	$I_{I} = -18 \text{ mA}$			-1.5			V
Vон	High-level output voltage	V <sub>ID</sub> = 200 mV, See Figure 6	$I_{OH} = -400  \mu A,$		2.7			٧
VOL	Low-level output voltage	V <sub>ID</sub> = -200 mV, See Figure 6	I <sub>OL</sub> = 8 mA,				0.45	٧
loz	High-impedance-state output current	V <sub>O</sub> = 0.4 V to 2.4 V	/		-20		20	μΑ
	Line Secret consent	Other input = 0 V,	V <sub>I</sub> = 12 V				1	0
i <sub>l</sub>	Line input current	See Note 5	V <sub>I</sub> = -7 V		-0.8			mA
lιΗ	High-level enable-input current	V <sub>IH</sub> = 2.7 V			-100			μΑ
I <sub>IL</sub>	Low-level enable-input current	V <sub>IL</sub> = 0.4 V			-100			μΑ
rı	Input resistance				12			kΩ
			Receiver enabled and driver disabled				3.9	mA
ICC	Supply current	V <sub>I</sub> = 0 or V <sub>CC</sub> , No load	Receiver and driver disabled	SN55LBC176, SN65LBC176, SN65LBC176Q			0.25	mA
				SN75LBC176			0.2	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

## switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L$ = 15 pF

PARAMETER		TEST CONDITIONS	SN55LBC176 SN65LBC176Q		SN65LBC176 SN75LBC176			UNIT
			MIN	MAX	MIN	TYP <sup>†</sup>	MAX	
tPLH	Propagation delay time, low- to high-level single-ended output	V <sub>ID</sub> = -1.5 V to 1.5 V, See Figure 7	11	37	11		33	ns
tPHL	Propagation delay time, high- to low-level single-ended output		11	37	11		33	ns
t <sub>sk(p)</sub>	Pulse skew ( tpLH - tpHL )			10		3	6	ns
<sup>t</sup> PZH	Output enable time to high level	0 5		35			35	ns
tPZL	Output enable time to low level	See Figure 8		35			30	ns
tPHZ	Output disable time from high level	See Figure 8		35			35	ns
tPLZ	Output disable time from low level	See Figure 6		35			30	ns

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .



<sup>&</sup>lt;sup>‡</sup> The algebraic convention, in which the less-positive (more-negative) limit is designated minimum, is used in this data sheet.

NOTE 5: This applies for both power on and power off. Refer to ANSI Standard RS-485 for exact conditions.

#### PARAMETER MEASUREMENT INFORMATION



Figure 1. Driver V<sub>OD</sub> and V<sub>OC</sub>

V<sub>test</sub>  $\mathbf{375}~\Omega$ 

Figure 2. Driver VOD3

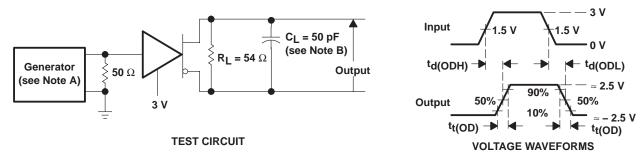


Figure 3. Driver Test Circuit and Voltage Waveforms

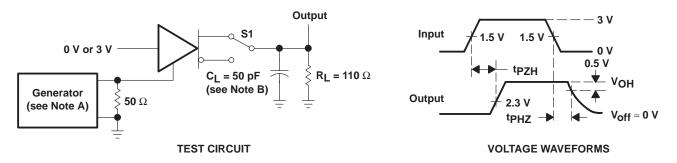


Figure 4. Driver Test Circuit and Voltage Waveforms

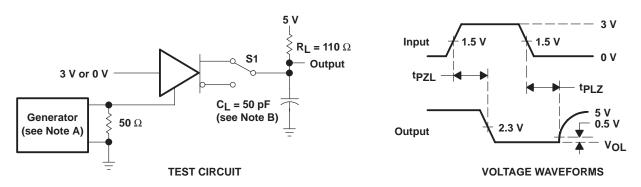


Figure 5. Driver Test Circuit and Voltage Waveforms

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_f \leq$  6 ns,  $t_f \leq$  6 ns,  $Z_{O} = 50 \Omega$ .
  - B. CL includes probe and jig capacitance.



#### PARAMETER MEASUREMENT INFORMATION

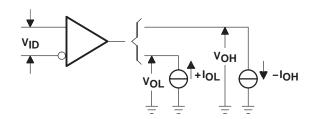
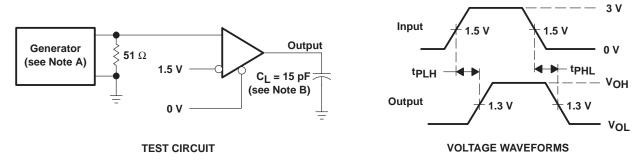


Figure 6. Receiver VOH and VOL



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_f \leq$  6 ns,  $t_f \leq$  8 ns,  $t_f \leq$  8 ns,  $t_f \leq$  9 ns,  $t_f$ 
  - B. C<sub>L</sub> includes probe and jig capacitance.

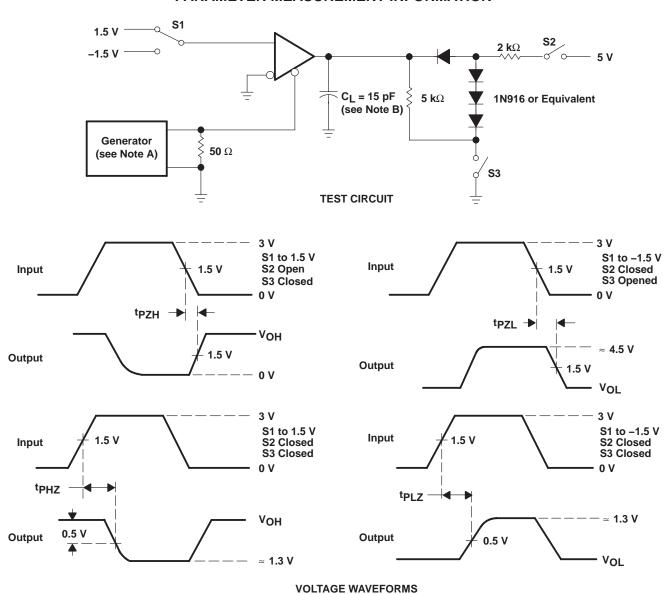
Figure 7. Receiver Test Circuit and Voltage Waveforms

#### THERMAL CHARACTERISTICS - D PACKAGE

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
handing to each install and the second and installed	Low-K board, no air flow	199.4			
Junction–to–ambient thermal reisistance, θ <sub>JA</sub> †	High-K board, no air flow		119		00004
Junction-to-board thermal reisistance, θJB	High-K board, no air flow		67		°C/W
Junction-to-case thermal reisistance, θ <sub>JC</sub>			46.6		
Average power dissipation, P(AVG)	R <sub>L</sub> = 54 $\Omega$ , input to D is 10 Mbps 50% duty cycle square wave, V <sub>CC</sub> = 5.25 V, T <sub>J</sub> = 130 °C.			330	mW
Thermal shutdown junction temperature, T <sub>SD</sub>			165		°C

<sup>†</sup> See TI application note literature number SZZA003, Package Thermal Characterization Methodologies, for an explanation of this parameter.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_{\Gamma} \leq$  6 ns,  $t_{\Gamma} \leq$  7 ns,  $t_{\Gamma} \leq$  8 ns,  $t_{\Gamma} \leq$  8 ns,  $t_{\Gamma} \leq$  9 ns,  $t_$ 

Figure 8. Receiver Test Circuit and Voltage Waveforms

B. C<sub>L</sub> includes probe and jig capacitance.

#### THERMAL CHARACTERISTICS OF IC PACKAGES

 $\Theta_{JA}$  (Junction-to-Ambient Thermal Resistance) is defined as the difference in junction temperature to ambient temperature divided by the operating power

 $\Theta_{JA}$  is NOT a constant and is a strong function of

- the PCB design (50% variation)
- altitude (20% variation)
- device power (5% variation)

 $\Theta_{JA}$  can be used to compare the thermal performance of packages if the specific test conditions are defined and used. Standardized testing includes specification of PCB construction, test chamber volume, sensor locations, and the thermal characteristics of holding fixtures.  $\Theta_{JA}$  is often misused when it is used to calculate junction temperatures for other installations.

TI uses two test PCBs as defined by JEDEC specifications. The low-k board gives *average* in-use condition thermal performance and consists of a single trace layer 25 mm long and 2-oz thick copper. The high-k board gives *best case* in-use condition and consists of two 1-oz buried power planes with a single trace layer 25 mm long with 2-oz thick copper. A 4% to 50% difference in  $\Theta_{JA}$  can be measured between these two test cards

 $\Theta_{JC}$  (Junction-to-Case Thermal Resistance) is defined as difference in junction temperature to case divided by the operating power. It is measured by putting the mounted package up against a copper block cold plate to force heat to flow from die, through the mold compound into the copper block.

 $\Theta_{JC}$  is a useful thermal characteristic when a heatsink is applied to package. It is NOT a useful characteristic to predict junction temperature as it provides pessimistic numbers if the case temperature is measured in a non-standard system and junction temperatures are backed out. It can be used with  $\Theta_{JB}$  in 1-dimensional thermal simulation of a package system.

 $\Theta_{JB}$  (Junction-to-Board Thermal Resistance) is defined to be the difference in the junction temperature and the PCB temperature at the center of the package (closest to the die) when the PCB is clamped in a cold–plate structure.  $\Theta_{JB}$  is only defined for the high-k test card.

 $\Theta_{JB}$  provides an overall thermal resistance between the die and the PCB. It includes a bit of the PCB thermal resistance (especially for BGA's with thermal balls) and can be used for simple 1-dimensional network analysis of package system (see Figure 1).

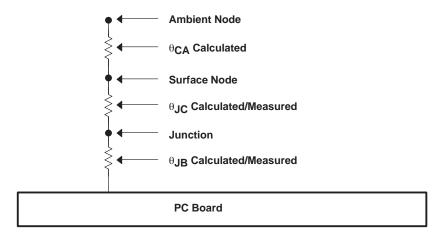


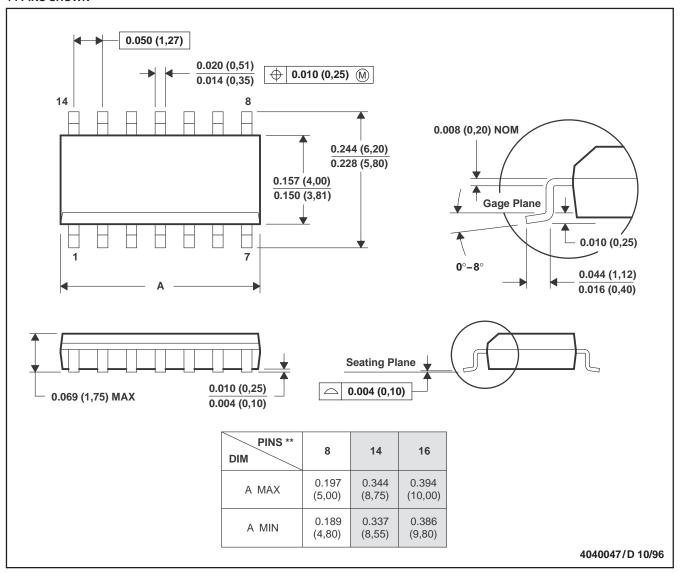
Figure 1. Thermal Resistance

#### **MECHANICAL INFORMATION**

#### D (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 14 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

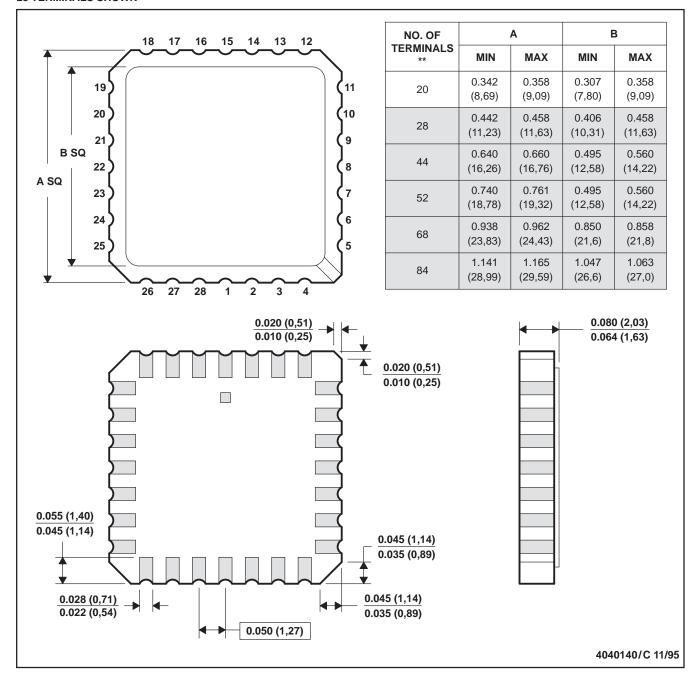
D. Falls within JEDEC MS-012

#### **MECHANICAL INFORMATION**

#### FK (S-CQCC-N\*\*)

#### 28 TERMINALS SHOWN

#### LEADLESS CERAMIC CHIP CARRIER



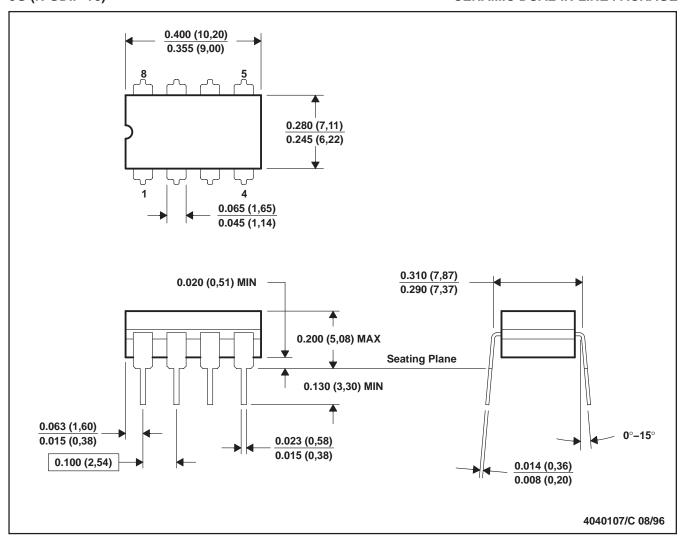
- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package can be hermetically sealed with a metal lid.
  - D. The terminals are gold-plated.
  - E. Falls within JEDEC MS-004



#### **MECHANICAL INFORMATION**

#### JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE PACKAGE**



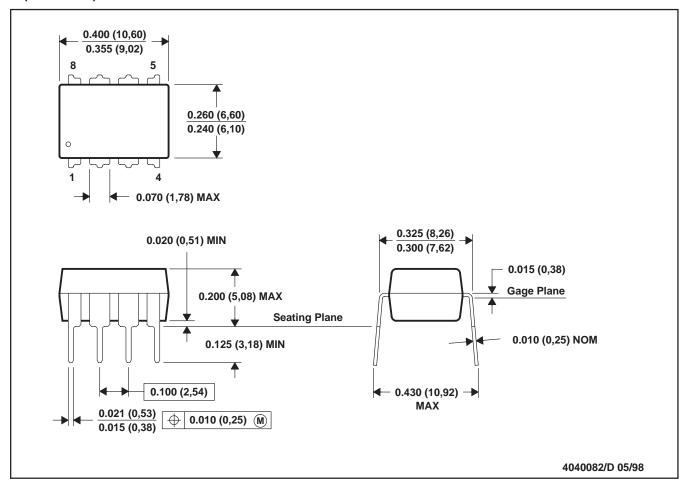
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL-STD-1835 GDIP1-T8

#### **MECHANICAL INFORMATION**

#### P (R-PDIP-T8)

#### **PLASTIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg\_info.htm





.com 11-Oct-2007

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-9318301Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9318301QPA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type
SN65LBC176D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC176DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC176DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC176DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC176P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65LBC176PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65LBC176QD	ACTIVE	SOIC	D	8	75	TBD	CU NIPDAU	Level-1-220C-UNLIM
SN65LBC176QDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC176QDR	ACTIVE	SOIC	D	8	2500	TBD	CU NIPDAU	Level-1-220C-UNLIM
SN65LBC176QDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC176D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC176DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC176DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC176DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC176P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC176PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SNJ55LBC176FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ55LBC176JG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	N / A for Pkg Type

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



#### PACKAGE OPTION ADDENDUM

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compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
		Overall width of the carrier tape
Γ	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC176DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65LBC176DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC176DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC176DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC176DR	SOIC	D	8	2500	340.5	338.1	20.6
SN65LBC176DR	SOIC	D	8	2500	346.0	346.0	29.0
SN75LBC176DR	SOIC	D	8	2500	346.0	346.0	29.0
SN75LBC176DR	SOIC	D	8	2500	340.5	338.1	20.6

#### FK (S-CQCC-N\*\*)

#### **28 TERMINAL SHOWN**

#### **LEADLESS CERAMIC CHIP CARRIER**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



## D (R-PDSO-G8)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



#### JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

#### P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

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